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**Atomic Force Microscopy Study of the Electrical  
Properties of Protein-Gold Nanoparticle Hybrids**

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# **Atomic Force Microscopy Study of the Electrical Properties of Protein-Gold Nanoparticle Hybrids**

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Thesis Approval




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## **Dedication**

This thesis is dedicated to my wonderful parents, Ibrahim and Maryam, who have raised me to be the person I am today. They have been with me every step of the way, through good times and bad. Thank you for all the unconditional love, guidance, and support that you have always given me, helping me to succeed and instilling in me the confidence that I am capable of doing anything I put my mind to. Thank you for everything. I love you!

Also I want to dedicate this thesis to my fiancé Anas for his love, patience, and his unending support along the way.

Mai Ibrahim Khalil Al-Maghalseh

**Declaration:**

I certify that this thesis submitted for the degree of Master is the result of my own research, except where otherwise acknowledged, and that this thesis (or any part of the same) has not been submitted for a higher degree to any other university or institution.

Signed:

A handwritten signature in blue ink, appearing to be 'M. Al-Maghalseh', written over a horizontal line. A vertical line extends downwards from the end of the signature.

Mai Ibrahim Khalil Al-Maghalseh

Date: 6/9/2009

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## Abstract

In the last decade, molecular nanoelectronics gained a growing attention in the field of electronic devices because of the need to have new devices with characteristics that overlap the limitations and disadvantages of the existed devices fabricated with common methods. In order to achieve building electronic devices using biological molecules it will be necessary to measure, control and understand the electron transport through these molecules. The purpose of this research was to study the morphological characteristics of a ring shaped like protein named stable protein 1 (SP1), and a building block that consists of gold nanoparticles (GNP) embedded in the central cavity of the SP1 protein. The morphological characteristics was studied on different four substrates which are mica, silicon, gold, and HOPG using Atomic Force Microscopy with its two modes; tapping and contact. Another aim of this research was to study the electrical characteristics of the SP1 and the building block (SP1-GNP) by performing direct electrical measurements for these molecules on HOPG substrate using conductive Atomic Force Microscopy measurement technique.

AFM results revealed that the average heights of SP1 molecules on mica and silicon were  $2.4 \pm 0.3$  and  $2.2 \pm 0.2$  nm respectively, while on gold and silicon SP1 monolayer was formed with average height equal to  $2 \pm 0.1$  nm. For SP1-GNP molecules their average heights were found to be  $3.7 \pm 0.4$  nm and  $3.3 \pm 0.1$  nm on mica and silicon respectively, but on gold and HOPG substrates a monolayer of SP1-GNP molecules was formed with average height of  $4 \pm 0.2$  nm above both substrates. The results of the direct electrical measurements showed an insulating current-voltage curves with different voltage ranges for both SP1 and SP1-GNP molecules when force-distance mode was performed with small load (Normal Force). The current-voltage curves performed with high load (N.F) showed a semiconductor behavior for SP1 molecules and an ohmic behavior for SP1-GNP molecules.

## Table of Contents

<b>1. Introduction and Motivation .....</b>	<b>1</b>
<b>2. Methods and Materials .....</b>	<b>7</b>
2.1 Atomic Force Microscopy.....	8
2.1.1 The Operation Principle of AFM.....	9
2.1.2 AFM Tips.....	10
2.1.3 Imaging Modes.....	11
2.2 Electrostatic Force Microscopy.....	13
2.3 Force vs Distance.....	14
2.4 Experimental Setup.....	15
2.5 Materials.....	16
2.5.1 SP1 Protein and SP1-GNP Complex.....	16
2.5.2 Substrates.....	19
2.6 Samples Preparation.....	20
2.6.1 SP1 Samples Preparation.....	20
2.6.2 SP1-GNP's Samples Preparation.....	20
<b>3. Results and Discussion.....</b>	<b>21</b>
3.1 Annealing of gold substrate.....	22
3.2 Morphological characterization of 73Cys-SP1 and 6His-SP1- GNP molecules.....	23
3.2.1 Morphological characterization of 73Cys-SP1 molecules on mica substrate.....	23
3.2.2 Morphological characterization of 73Cys-SP1 molecules on silicon substrate.....	26
3.2.3 Morphological characterization of 73Cys-SP1 molecules on gold substrate.....	28
3.2.4 Morphological characterization of 73Cys-SP1	



	molecules on HOPG substrate.....	29
3.2.5	Morphological characterization of 6His-SP1-GNP molecules on mica substrate.....	30
3.2.6	Morphological characterization of 6His-SP1-GNP molecules on silicon substrate.....	32
3.2.7	Morphological characterization of 6His-SP1-GNP molecules on gold substrate.....	34
3.2.8	Morphological characterization of 6His-SP1-GNP molecules on HOPG substrate.....	35
3.3	Electrical characterization of 73Cys-SP1 and 6His-SP1-GNP molecules.....	39
<b>4.</b>	<b>Conclusion and Future Work.....</b>	<b>48</b>
4.1	Conclusion.....	49
4.2	Future Work.....	49
	<b>References.....</b>	<b>50</b>

## List of Figures

<b>Figure Number</b>	<b>Figure Name</b>	<b>Page</b>
Figure 1.1	<i>Plot of CPU transistor counts against dates of introduction.</i>	3
Figure 2.1	<i>Forces between the AFM tip and the sample as a function of the tip-sample distance.</i>	8
Figure 2.2	<i>A schematic representation of AFM main components of the system.</i>	9
Figure 2.3	<i>SEM images of AFM tips.</i>	10
Figure 2.4	<i>A schematic of Electrostatic Force Microscopy operation.</i>	13
Figure 2.5	<i>A force distance plot showing tips deflection in each point above the sample, a snap-in and a pull-off point are not in the same distance due to capillary forces acting on the tip forcing to apply bigger load to disconnect the tip from the surface.</i>	14
Figure 2.6	<i>A schematics of the experiment setup.</i>	15
Figure 2.7	<i>(a) SPI monomer with N-termini, (b) SPI dimer composed of two SPI monomers, (c) Crystal structure of SPI molecule with 12 N-termini, (d) Electron microscopy of SPI molecule.</i>	17
Figure 2.8	<i>(a) SPI monomer with Cys group, (b) Cys groups on SPI dodecamer, (c) SPI monomer with His group on N-termini, (d) His groups on 6 N-termini of SPI dodecamer, (e) GNP bind to the center of SPI molecule, (f) 3D image of SPI-GNP complex.</i>	18
Figure 3.1	<i>AFM topography images of (a) gold before annealing process; scanning size <math>1 \times 1 \mu\text{m}^2</math>, (b) and (c) after annealing; scanning size <math>4 \times 4 \mu\text{m}^2</math>, (d) Au (111) terraces after annealing.</i>	22

Figure 3.2	<i>AFM topography images of 73Cys-SPI molecules on mica substrate on different areas, acquired in tapping mode: (a) 2x2 <math>\mu\text{m}^2</math>, (b) 1x1 <math>\mu\text{m}^2</math>, (c) 1x1 <math>\mu\text{m}^2</math>, and (d) height profiles of SPI molecules.</i>	24
Figure 3.3	<i>(a) AFM topography image of 73Cys-SPI molecules on mica substrate, (b) flooding image of the topograpgy (a) shows the SPI molecules with heights range from 2 nm to 3.3 nm, (c) height distribution for the SPI molecules in image (a), and (d) histogram shows height distribution of SPI molecules in the flooding image (b).</i>	25
Figure 3.4	<i>AFM topography images of 73Cys-SPI molecules on silicon substrate on different areas, acquired in tapping mode: (a) 2x2 <math>\mu\text{m}^2</math>, (b) 1.2x1.2 <math>\mu\text{m}^2</math>, (c) 700x700 <math>\text{nm}^2</math>, and (d) height profiles of SPI molecules.</i>	26
Figure 3.5	<i>(a) AFM topography image of 73Cys-SPI molecules on silicon substrate, (b) flooding image of the topograpgy (a) shows the SPI molecules with heights range from 2 nm to 2.6 nm, (c) height distribution for the SPI molecules in image (a), and (d) histogram shows height distribution of SPI molecules in the flooding image (b).</i>	27
Figure 3.6	<i>AFM topography images of 73Cys-SPI molecules on annealed gold substrate, on different areas, acquired in tapping and contact modes, the scratched regions were done using Si OMLC-AC tip, and the cross-section height profiles of the scratched areas: (a) 2x2 <math>\mu\text{m}^2</math>, (b) 3.2x3.25 <math>\mu\text{m}^2</math>, (d) and (e) 1.5x1.5 <math>\mu\text{m}^2</math>, (g) and (h) 1.2x1.2 <math>\mu\text{m}^2</math>.</i>	28
Figure 3.7	<i>AFM topography images of 73Cys-SPI molecules on HOPG substrate on different areas, acquired in tapping mode: (a) 2x2 <math>\mu\text{m}^2</math>, (b) height profile, (c) 1.1 <math>\mu\text{m}^2</math>, and (d) 600x600 nm.</i>	29
Figure 3.8	<i>AFM topography images of 6His-SPI-GNP molecules on mica substrate on different areas, acquired in tapping mode: (a) and (b) 1.4x1.4 <math>\mu\text{m}^2</math>, (c) 600x600 <math>\text{nm}^2</math>, and (d) height profiles of 6His-SPI-GNP molecules.</i>	30
Figure 3.9	<i>(a) AFM topography image of 6His-SPI-GNP molecules on mica substrate, (b) flooding image of the topograpgy (a) shows the SPI-GNP molecules with heights range from 2.5 nm to 10.7 nm, (c) height distribution for the SPI-GNP molecules in image (a), and (d) histogram</i>	31

*shows height distribution of the SPI-GNP molecules in the flooding image (b).*

- Figure 3.10 *AFM topography images of 6His-SPI-GNP molecules on silicon substrate on different areas, acquired in tapping mode: (a)  $2 \times 2 \mu\text{m}^2$ , (b)  $1.4 \times 1.4 \mu\text{m}^2$ , (c)  $700 \times 700 \text{nm}^2$ , and (d) height profiles of 6His-SPI-GNP molecules.* 32
- Figure 3.11 *(a) AFM topography image of 6His-SPI-GNP molecules on silicon substrate, (b) flooding image of the topography (a) shows the SPI molecules with heights range from 2.5 nm to 6.3 nm, (c) height distribution for the SPI-GNP molecules in image (a), and (d) histogram shows height distribution of SPI-GNP molecules in the flooding image (b).* 33
- Figure 3.12 *AFM topography images of 6His-SPI-GNP molecules on annealed gold substrate, on different areas, acquired in tapping and contact modes, the scratched region was done using Si ElectriMulti75-G tip, and the cross-section height profile of the scratched area: (a)  $4 \times 4 \mu\text{m}^2$ , (b)  $3 \times 3 \mu\text{m}^2$ , (d) and (e)  $1.5 \times 1.5 \mu\text{m}^2$ .* 34
- Figure 3.13 *AFM topography images of 6His-SPI-GNP molecules on HOPG substrate, on different areas, acquired in tapping and contact modes, the scratched region was done using Si ElectriMulti75-G tip, and the cross-section height profile of the scratched area: (a)  $800 \times 800 \text{nm}^2$ , (b)  $500 \times 500 \text{nm}^2$ , and (c)  $1.5 \times 1.5 \mu\text{m}^2$ .* 35
- Figure 3.14 *A schematic of SPI and SPI-GNP standing tubes.* 38
- Figure 3.15 *F-d curves (a) with high normal force, (b) with small normal force on bare gold; the green and red lines represent approach and withdrawal deflection of the oscillated tip respectively; in the last point of the approach, the I-V measurements can be performed; the slope of the red line in (b) shows the presence of adhesion and capillary forces between the tip and the gold.* 40
- Figure 3.16 *Results of the combined F-d/ I-V mode on bare gold, (a) F-d curve on gold with small normal force of the tip on the sample, and (b) I-V curve for gold with voltage sweep from -1.5v to 1.5v.* 40

Figure 3.17	<i>Result of the combined F-d/ I-V mode on SPI molecules, (a) SPI molecules that the measurements have been done on, (b) no pressing in F-d curve (green line), and (c) 10 I-V curves with zero current and voltage sweep from -1.5v to 1.5v.</i>	41
Figure 3.18	<i>Result of the combined F-d/I-V mode on SPI-GNP molecules showed, (a) SPI-GNP molecules that the measurements have been done on, (b) no pressing in F-d curve (green line), and (c) 10 I-V curves with zero current and voltage sweep from -2v to 2v.</i>	42
Figure 3.19	<i>Result of the combined F-d/I-V mode on SPI molecules, (a) SPI molecules that the measurements have been done on, (b) pressing in F-d curve, the SPI molecule is pushed to direct contact with the HOPG substrate, and (c)-(f) the I-V curves with sweep voltage from -1.5v to 1.5v and -2v to 2v.</i>	43
Figure 3.20	<i>Result of the combined F-d/I-V mode on SPI-GNP molecules, (a) SPI-GNP molecules that the measurements have been done on, (b) pressing in F-d curve, the GNP is pushed to direct contact with the HOPG substrate, and (c)-(f) the I-V curves with sweep voltage from -2v to 2v.</i>	44
Figure 3.21	<i>A comparison between two I-V curves, (a) for SPI molecule showing sigmoidal shape, (b) for SPI-GNP molecule showing an ohmic signal.</i>	45
Figure 3.22	<i>A schematic of metal-protein-metal junction.</i>	46
Figure 3.23	<i>A schematic of a nanowire from SPI-GNP molecules.</i>	47

## List of Tables

<b>Table Number</b>	<b>Table Name</b>	<b>Page</b>
Table 3.1	The dimensions of SP1 and SP1-GNP molecules obtained by different methods.	36
Table 3.2	The dimensions of SP1 and SP1-GNP molecules obtained by AFM tapping mode on different four substrates.	37
Table 3.3	Electrical prosperities of SP1 and SP1-GNP molecules obtained by EFM and I-V.	45

## Abbreviations

STM	Scanning Tunneling Microscopy
SPM	Scanning Probe Microscopes
AFM	Atomic Force Microscopy
DNA	Deoxyribonucleic Acid
NP	Nanoparticle
GNP	Gold Nanoparticle
SP1	Stable Protein One
EFM	Electrostatic Force Microscopy
His	Histidine
Cys	Cystein
HOPG	Hydrophobic Highly Oriented Pyrolytic Graphite
PSD	Position Sensitive Detector
DSP	Digital Signal Processing
VDW	Van der Waals
F-d	Force versus Distance
JIC	Jump In (To) Contact or “Snap-In” Point
C-AFM	Conductive AFM
I-V	Current- Voltage
KDa	Kilodalton
N.F	Normal Force
T.D.W	Triple Distilled Water